

High-Vin, High-Efficiency Power Solution Using DC/DC Converter With DVFS

Ambreesh Tripathi

PMP - DC/DC Low-Power Converters

ABSTRACT

This reference design is intended for users designing with the TMS320C6742, TMS320C6746, TMS320C6748, or OMAP-L138 processor. Using sequenced power supplies, this reference design describes a system having a 12-V input voltage and a high-efficiency dc/dc converter with integrated FETs and dynamic voltage and frequency scaling (DVFS) for a small, simple design.

Sequenced power supply architectures are becoming commonplace in high-performance microprocessor and digital signal processor (DSP) systems. To save power and increase processing speeds, processor cores have smaller geometry cells and require lower supply voltages than the system bus voltages. Power management in these systems requires special attention. This application report addresses these topics and suggests solutions for output voltage sequencing.

Contents

1	Introduction	2
2	Power Requirements	2
3	Features	3
4	Bill of Materials	6

List of Figures

1	PMP4976 Reference Design Schematic	4
2	Optional Circuit for DVDD_A, DVDD_B, and DVDD_C	5
3	Sequencing in Start-up Waveform	7
4	Efficiency vs Output Current	7
5	Efficiency vs Output Current	7
6	Efficiency vs Output Current	7
7	Efficiency vs Output Current	7

List of Tables

1	General Requirements	2
2	PMP4976 Bill of Materials	6

1



1 Introduction

In dual voltage architectures, coordinated management of power supplies is necessary to avoid potential problems and ensure reliable performance. Power supply designers must consider the timing and voltage differences between core and input/output (I/O) voltage supplies during power-up and power-down operations.

Sequencing refers to the order, timing, and differential in which the two voltage rails are powered up and down. A system designed without proper sequencing may be at risk for two types of failures. The first of these represents a threat to the long-term reliability of the dual voltage device, whereas the second is more immediate, with the possibility of damaging interface circuits in the processor or system devices such as memory, logic, or data converter integrated circuits (IC).

Another potential problem with improper supply sequencing is bus contention. Bus contention is a condition in which the processor and another device both attempt to control a bidirectional bus during power up. Bus contention may also affect I/O reliability. Power supply designers must check the requirements regarding bus contention for individual devices.

The power-on sequencing for the OMAP-L138, TMS320C6742, TMS320C6746, and TMS320C6748 are shown in Table 1. None of the supplies for these devices require a specific voltage ramp rate as long as the 3.3-V rail does not exceeds the 1.8-V rail by more than 2 V.

In order to reduce the power consumption of the processor core, dynamic voltage and frequency scaling (DVFS) is used in the reference design. DVFS is a power management technique used while active processing is going on in the system-on-chip (SoC), which matches the operating frequency of the hardware to the performance requirement of the active application scenario. Whenever clock frequencies are lowered, operating voltages are also lowered to achieve power savings. In the reference design, the TPS62353 is used, which can scale its output voltage.

2 **Power Requirements**

The power requirements are as specified in the following table.

	PIN NAME	VOLTAGE ^{(1) (2)} (V)	lmax (mA)	TOLERANCE	SEQUENCING ORDER	TIMING DELAY
I/O	RTC_CVDD	1.2	1	-25%, +10%	1 ⁽³⁾	
Core	CVDD ⁽⁴⁾	1.0 / 1.1 / 1.2	600	-9.75%, +10%	2	
I/O	RVDD, PLL0_VDDA, PLL1_VDDA, SATA_VDD, USB_CVDD, USB0_VDDA12	1.2	200	-5%, +10%	3	
I/O	USB0_VDDA18, USB1_VDDA18, DDR_DVDD18, SATA_VDDR, DVDD18	1.8	180	±5%	4	
I/O	USB0_VDDA33, USB1_VDDA33	3.3	24	±5%	5	
I/O	DVDD3318_A, DVDD3318_B, DVDD3318_C	1.8 / 3.3	50 / 90 ⁽⁵⁾	±5%	4 / 5	

Table 1. General Requirements

⁽¹⁾ If 1.8-V LVCMOS is used, power rails up with the 1.8-V rails. If 3.3-V LVCMOS is used, power it up with the ANALOG33 rails (VDDA33_USB0/1).

⁽²⁾ No specific voltage ramp rate is required for any of the supplies LVCMOS33 (USB0_VDDA33, USB1_VDDA33) as long as STATIC18 (USB0_VDDA18, USB1_VDDA18, DDR_DVDD18, SATA_VDDR, DVDD18) never exceeds more than 2 V.

⁽³⁾ If RTC is not used/maintained on a separate supply, it can be included in the STATIC12 (fixed 1.2 V) group.

⁽⁴⁾ If using CVDD at fixed 1.2 V, all 1.2-V rails may be combined.

⁽⁵⁾ If DVDD3318_A, B, and C are powered independently, maximum power for each rail is 1/3 above maximum power.

NanoFree is a trademark of Texas Instruments.

3 Features

The design uses the following high-efficiency dc/dc converters with integrated FETs.

	HIGH EFFICIENCY (With DVFS)
INPUT VOLTAGE	~12 V/3.3 V
OUTPUT VOLTAGES	
Core 1.2 V at 600 mA	TPS62353
Fixed 1.2 V + VRTC at 251 mA	TPS62232
1.8 V at 230 mA	TPS62231
3.3 V at 115 mA	TPS62111

In the preceding table, VRTC is included in the STATIC12 (fixed 1.2-V) group.

TPS62353

- 88% efficiency at 3-MHz operation
- Output peak current up to 800 mA
- 3-MHz fixed frequency operation
- Best in class load and line transient
- ±2% PWM dc voltage accuracy
- Efficiency optimized Power-Save mode
- Transient optimized Power-Save mode
- Fixed 1.2-V output eliminates need for external voltage-setting resistors
- Available in a 10-pin QFN (3 × 3 mm) 12-pin NanoFree™ (CSP) packaging

TPS62231 and TPS62232

- 3-MHz switch frequency
- Up to 94% efficiency
- Output peak current up to 500 mA
- Small external output filter components (1 μ H/4.7 μ F)
- Small 1 × 1,5 × 0,6 mm 3 SON package
- Fixed 1.8-V and 1.2-V output, respectively, eliminates need for external voltage-setting resistors

TPS62111

- High-efficiency synchronous step-down converter with up to 95% efficiency
- Up to 1.5-A output current
- · High efficiency over a wide load-current range due to PFM/PWM operation mode
- Fixed 3.3-V output eliminates need for external voltage-setting resistors

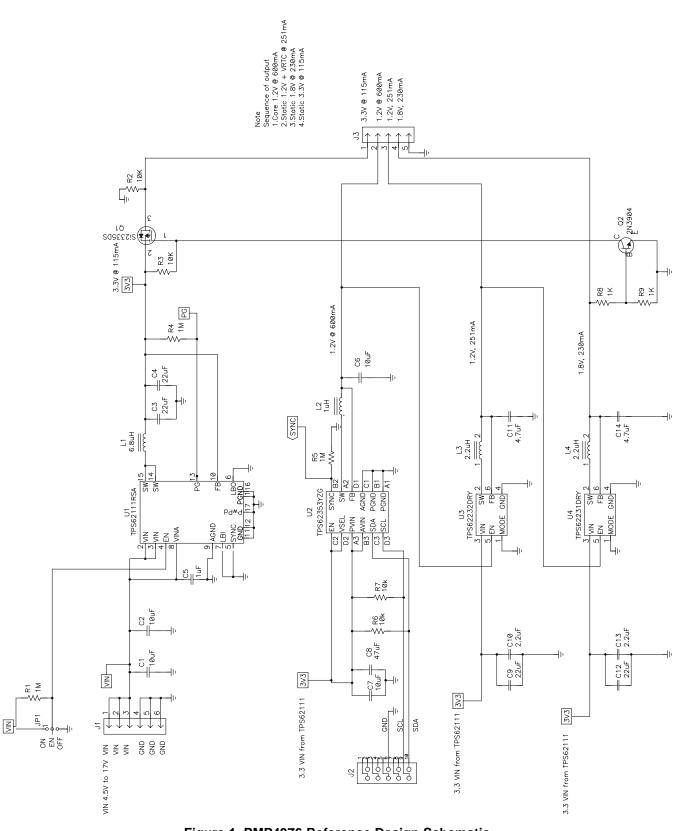
More information on the devices can be found in the data sheets.

- TPS62111, <u>SLVS585</u>
- TPS62231 and TPS62232, <u>SLVS941</u>
- TPS62353, <u>SLVS540</u>

3

4

www.ti.com

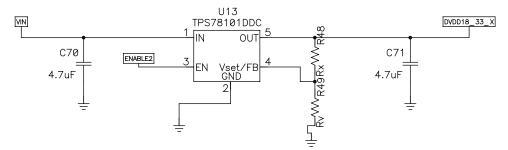






5

Proper sequencing is ensured in the design with the use of a NPN transistor and a P-channel MOSFET. As required, Core 1.2 V at 600 mA comes first, and is followed by Static 1.2 V + VRTC at 251 mA. Then comes Static 1.8 V at 230 mA, which in turn pulls down the gate of a P-channel MOSFET with the use of a NPN transistor. Last, Static 3.3 V at 115 mA comes up.



- (1) Use three such LDOs to power up DVDDA, DVDDB, and DVDDC. (It can be either 1.8 V or 3.3 V.)
- (2) $Rx = 0.499 M\Omega$, $Ry = 1 M\Omega$ for Vout = 1.8 V
- (3) $Rx = 1.8 M\Omega$, $Ry = 1 M\Omega$ for Vout = 3.3 V
- (4) For proper sequencing of output, the enable of the LDOs are fed either from a 1.2-V output from TPS62232 if DVDDX is 1.8 V or from a 1.8-V output from TPS62231 if DVDDX is 3.3 V.

Figure 2. Optional Circuit for DVDD_A, DVDD_B, and DVDD_C

Bill of Materials

4 Bill of Materials

Table 2. PMP4976 Bill of Materials

Count	RefDes	Value	Description	Size	Part Number	MFR	AREA
2	C1	10 μF	Capacitor, Ceramic, 25V, X5R, 20%	1206	C3216X5R1E106	TDK	15390
	C2	10 μF	Capacitor, Ceramic, 25V, X5R, 20%	1206	C3216X5R1E106	TDK	15390
2	C3	22 μF	Capacitor, Ceramic, 10V, X5R, 20%	1206	C3216X5R1A226	TDK	15390
	C4	22 μF	Capacitor, Ceramic, 10V, X5R, 20%	1206	C3216X5R1A226	TDK	15390
1	C5	1 μF	Capacitor, Ceramic, 25V, X7R, 10%	603	C1608X7R1E105K	TDK	5650
2	C6	10 μF	Capacitor, Ceramic, 6.3V, X5R, 10%	603	C1608X5R0J106KT	TDK	5650
	C7	10 μF	Capacitor, Ceramic, 6.3V, X5R, 10%	603	C1608X5R0J106KT	TDK	5650
1	C8	47 μF	Capacitor, Ceramic, 10V, X5R, 20%	1812	C4532X5R1A476M	TDK	43,360
2	C9	22 μF	Capacitor, Ceramic, 10V, X5R, 20%	1210	Std	Std	83,600
2	C10	2.2 μF	Capacitor, Ceramic, 6.3V, X5R, 20%	402	JDK105BJ225MV	Taiyo Yuden	2800
2	C11	4.7 μF	Capacitor, Ceramic, 6.3V, X5R, 20%	402	JDK105BJ475MV	Taiyo Yuden	2800
	C12	22 μF	Capacitor, Ceramic, 10V, X5R, 20%	1210	Std	Std	83,600
	C13	2.2 μF	Capacitor, Ceramic, 6.3V, X5R, 20%	402	JDK105BJ225MV	Taiyo Yuden	2800
	C14	4.7 μF	Capacitor, Ceramic, 6.3V, X5R, 20%	402	JDK105BJ475MV	Taiyo Yuden	2800
1	J1	PTC36SAAN	Header, Male 6-pin, 100mil spacing, (36-pin strip)	0.100 inch × 6	PTC36SAAN	Sullins	70000
1	J2	2510-6002UB	Connector, Male Straight 2×10 pin, 100mil spacing, 4 Wall	0.338 × 0.788	2510-6002UB	3M	301.02 4
1	J3	PEC36SAAN	Header, Male 5-pin, 100mil spacing, (36-pin strip)	0.100 inch × 5	PEC36SAAN	Sullins	60000
1	JP1	PTC36SAAN	Header, 3-pin, 100mil spacing, (36-pin strip)	0.100 × 3	PTC36SAAN	Sullins	34100
1	L1	6.8 μΗ	Inductor, SMT, 3.0A, 97 mΩ	0.276 × 0.276 inch	HA3808-AL	Coiltronics	90000
1	L2	1 μΗ	Inductor, SMT, 1.6A, ±30%	0.118 × 0.118	LPS3010-102NLC	Coilcraft	26,560
2	L3	2.2 μΗ	Inductor, SMT, 0.7A, 230-mΩ	805	MIPSZ20120D2R2	FDK	10160
	L4	2.2 μΗ	Inductor, SMT, 0.7A, 230-mΩ	805	MIPSZ20120D2R2	FDK	10160
1	Q1	Si2335DS	MOSFET, P-ch, -12 V, 4 A, 51 mΩ	SOT23	Si2335DS	Vishay	14105
1	Q2	2N3904	Transistor, NPN, 40V, 200mA, 625mW	TO-92	2N3904	Fairchild	37800
1	R1	1M	Resistor, Chip, 1/16-W, 1%	603	Std	Std	9100
2	R2	10K	Resistor, Chip, 1/16W, x%	603	Std	Std	5,650
	R3	10K	Resistor, Chip, 1/16W, x%	603	Std	Std	5,650
1	R4	1M	Resistor, Chip, 1/16W, x%	603	Std	Std	5,650
1	R5	1M	Resistor, Chip, 1/16W, 1%	603	Std	Std	5650
2	R6	10k	Resistor, Chip, 1/16W, 1%	603	Std	Std	5650
	R7	10k	Resistor, Chip, 1/16W, 1%	603	Std	Std	5650
2	R8	1K	Resistor, Chip, 1/16W, x%	603	Std	Std	5,650
	R9	1K	Resistor, Chip, 1/16W, x%	603	Std	Std	5,650
1	U1	TPS62111RSA	IC, Synchronous Step-Down Converter, 17V, 1.2A	QFN-16	TPS62111RSA	ті	54289
1	U2	TPS62353YZG	IC, 3MHz Synchronous Step Down Converter with I ² C, 800mA	CSP-12	TPS62353YZG	ті	12,000
1	U3	TPS62232DRY	IC, 3MHz Ultra Small Step Down Converter, x.x V	QFN	TPS62232DRY	TI	6020
1	U4	TPS62231DRY	IC, 3MHz Ultra Small Step Down Converter, x.x V	QFN	TPS62232DRY	ТІ	6020

Notes: 1. These assemblies are ESD sensitive, ESD precautions shall be observed.

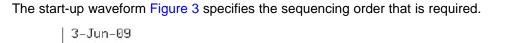
2. These assemblies must be clean and free from flux and all contaminants. Failure to use clean flux is unacceptable.

3. These assemblies must comply with workmanship standards IPC-A-610 Class 2.

4. Reference designators marked with an asterisk (***) cannot be substituted. All other components can be substituted with equivalent MFG's components.



4.1 Test Result



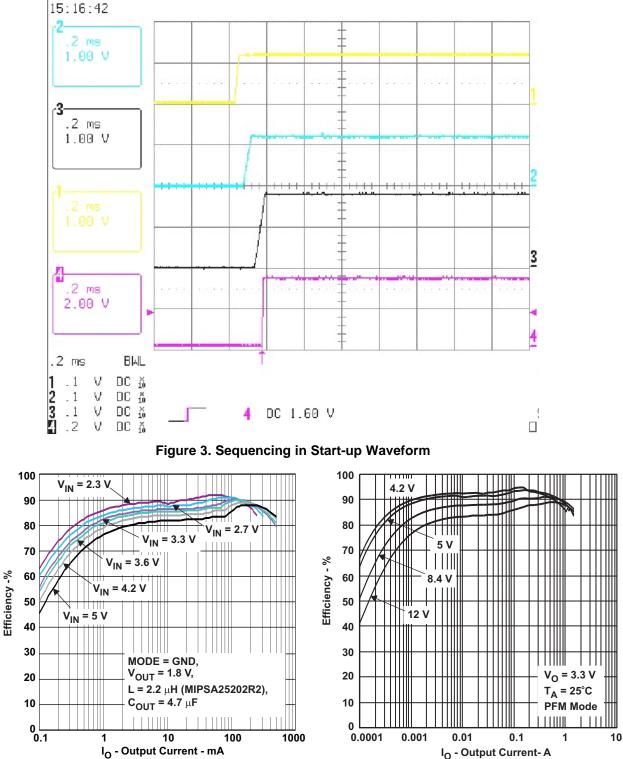
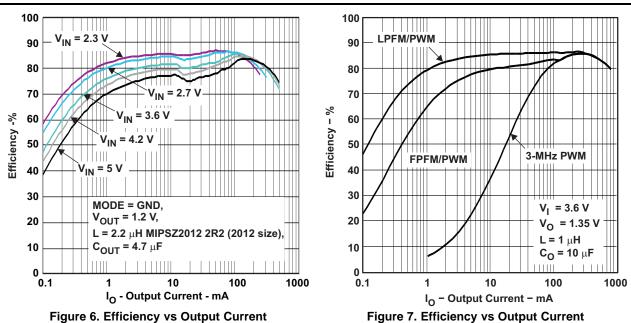


Figure 4. Efficiency vs Output Current





www.ti.com



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DLP® Products	www.dlp.com	Communications and Telecom	www.ti.com/communications
DSP	dsp.ti.com	Computers and Peripherals	www.ti.com/computers
Clocks and Timers	www.ti.com/clocks	Consumer Electronics	www.ti.com/consumer-apps
Interface	interface.ti.com	Energy	www.ti.com/energy
Logic	logic.ti.com	Industrial	www.ti.com/industrial
Power Mgmt	power.ti.com	Medical	www.ti.com/medical
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
RFID	www.ti-rfid.com	Space, Avionics & Defense	www.ti.com/space-avionics-defense
RF/IF and ZigBee® Solutions	www.ti.com/lprf	Video and Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless-apps

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2010, Texas Instruments Incorporated